



DMG3415UFY4

P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
 - $39m\Omega @ V_{GS} = -4.5V$
 - $52m\Omega$ @ $V_{GS} = -2.5V$
 - $65m\Omega @ V_{GS} = -1.8V$
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- ESD Protected Up To 3kV
- "Green" Device, Halogen and Antimony Free (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

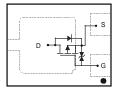
Mechanical Data

- Case: DFN2015H4-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)









TOP VIEW

BOTTOM VIEW

Internal Schematic

Maximum Ratings @TA = 25°C unless otherwise specified

Charact	eristic		Symbol	Value	Units
Drain-Source Voltage		V _{DSS}	-16	V	
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 3)	Steady State	T _A = 25°C T _A = 70°C	I _D	-2.5 -2.2	А
Pulsed Drain Current (Note 4)			I _{DM}	-12	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	P _D	0.49	W
Thermal Resistance, Junction to Ambient @T _A = 25°C	$R_{\theta JA}$	250.7	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB with 2oz. Copper and test pulse width t ≤ 10s.
- 4. Repetitive rating, pulse width limited by junction temperature.

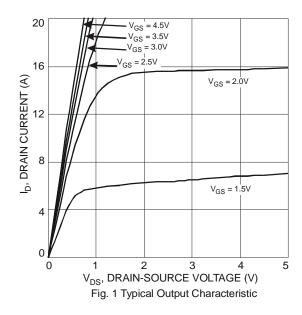


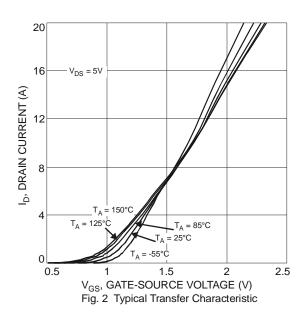
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV _{DSS}	-16	_		V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}		_	-1.0	μΑ	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage			_	±10 ±500	μA nA	$V_{GS} = \pm 8V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)					10.4	VGS - ±0V, VDS - 0V	
Gate Threshold Voltage	V _{GS(th)}	-0.3	-0.55	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
			31	39		$V_{GS} = -4.5V$, $I_{D} = -4.0A$	
Static Drain-Source On-Resistance	R _{DS (ON)}	_	40	52	mΩ	$V_{GS} = -2.5V, I_D = -3.5A$	
	, ,		51	65		$V_{GS} = -1.8V, I_D = -2.0A$	
Forward Transfer Admittance	Y _{fs}		7.9		S	$V_{DS} = -5V$, $I_{D} = -2.5A$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	Ciss	_	281.9	_	pF	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Output Capacitance	Coss		152.0	_	pF	$V_{DS} = -10V, V_{GS} = 0V$ -f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}		37.9		pF	1 = 1.01/1112	
Gate Resistnace	R_g		250		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
SWITCHING CHARACTERISTICS (Note 6)							
Total Gate Charge	Q_g		10	_	nC		
Gate-Source Charge	Q_{gs}		1.5		nC	$V_{GS} = -4.5V$, $V_{DS} = -10V$, $I_{D} = -4A$	
Gate-Drain Charge	Q_{gd}		2.4		nC		
Turn-On Delay Time	t _{D(on)}		79.0	_	ns		
Turn-On Rise Time	t _r		175.2		ns	$V_{DS} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t _{D(off)}	_	884.5	_	ns	$R_D = 2.5\Omega$, $R_G = 3.0\Omega$	
Turn-Off Fall Time	t _f	_	568		ns		

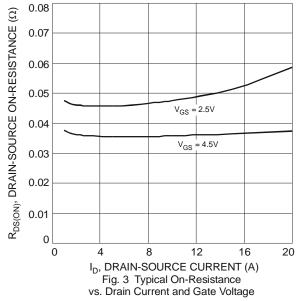
Notes:

- 5. Short duration pulse test used to minimize self-heating effect.
- 6. Guaranteed by design. Not subject to production testing.









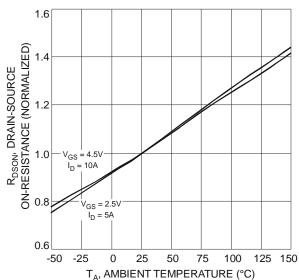


Fig. 5 On-Resistance Variation with Temperature

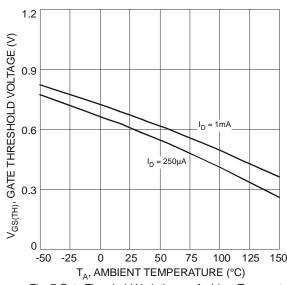


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

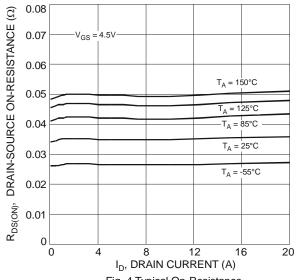


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

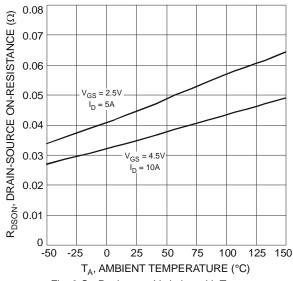


Fig. 6 On-Resistance Variation with Temperature

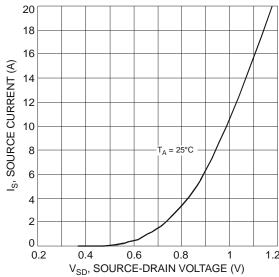


Fig. 8 Diode Forward Voltage vs. Current



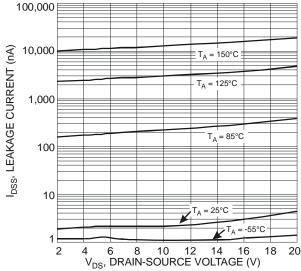
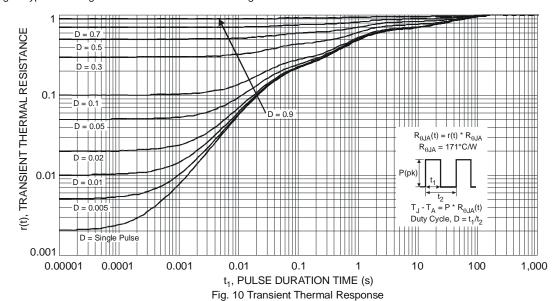


Fig. 9 Typical Leakage Current vs. Drain-Source Voltage



Ordering Information (Note 7)

Ī	Part Number	Case	Packaging		
	DMG3415UFY4-7	DFN2015H4-3	3000/Tape & Reel		

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

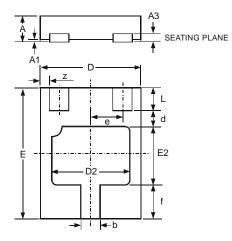
34P YM 34P = Marking Code YM = Date Code Marking Y = Year (ex: W = 2009) M = Month (ex: 9 = September)

Date Code Key

Year	2009	9	2010		2011	20	12	2013		2014		2015
Code	W		Χ		Υ		Z	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

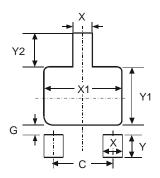


Package Outline Dimensions



DFN2015H4-3						
Dim	Min	Max	Тур			
Α	_	0.40	-			
A1	0	0.05	0.02			
A3	_	_	0.13			
b	0.20	0.30	0.25			
d	ı	_	0.30			
D	1.45	1.575	1.50			
D2	1.00	1.20	1.10			
е	ı	_	0.50			
Е	1.95	2.075	2.00			
E2	0.70	0.90	0.80			
f	_	_	0.60			
L	0.25	0.35	0.30			
z	_	_	0.125			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
С	1.00
G	0.15
X	0.31
X1	1.30
Υ	0.50
Y1	1.00
Y2	0.65



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